



Docket No.: 60188-402

**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In application of

: Response Under 37 CFR 1.116 - Expedited Procedure  
: Customer Number: 20277

ODAKE, YOSHINORI, et al.

: Confirmation Number: 6382

Application No.: 09/987,001

: Group Art Unit: 2812

Filed: November 13, 2001

: Examiner: Richard A. BOOTH

For: METHOD OF FABRICATING NONVOLATILE SEMICONDUCTOR MEMORY DEVICE

Mail Stop AF

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Dear Sir:

Transmitted herewith is an Amendment in the above-identified application.

- ☒ No additional fee is required.  
☐ Applicant is entitled to small entity status under 37 CFR 1.27  
☐ Also attached:

The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	17	20	0	\$18.00 =	\$0.00
Independent Claims	1	3	0	\$88.00 =	\$0.00
Multiple claims newly presented					\$0.00
Fee for extension of time					\$0.00
					\$0.00
Total of Above Calculations					\$0.00

- ☐ Please charge my Deposit Account No. 500417 in the amount of \$0.00. An additional copy of this transmittal sheet is submitted herewith.
- ☒ The Commissioner is hereby authorized to charge payment of any fees associated with this communication or credit any overpayment, to Deposit Account No. 500417, including any filing fees under 37 CFR 1.16 for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

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**Date: October 28, 2004**

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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**RESPONSE UNDER 37 C.F.R. 1.116**  
**EXPEDITED PROCEDURE**

In re Application of	:	Customer Number: 20277
ODAKE, YOSHINORI, et al.	:	Confirmation Number: 6382
Application No.: 09/987,001	:	Group Art Unit: 2812
Filed: November 13, 2001	:	Examiner: Richard A. BOOTH

For: METHOD OF FABRICATING NONVOLATILE SEMICONDUCTOR MEMORY DEVICE

**AMENDMENT UNDER 37 C.F.R. 1.116**

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In response to the final Office Action dated August 23, 2004, having a shortened statutory period for response set to expire on November 23, 2004, reconsideration of the above-identified application is respectfully requested in view of the following amendment and remarks.